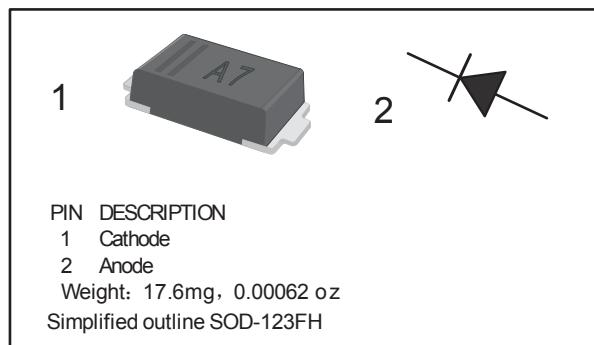


General Purpose Silicon Rectifiers

1N4001FH ~ 1N4007FH

■ Features

- Surface Mount General Purpose Silicon Rectifiers
- Reverse Voltage - 50 to 1000 V
- Forward Current: 1 A



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	1N4001FH	1N4002FH	1N4003FH	1N4004FH	1N4005FH	1N4006FH	1N4007FH	Unit	
Repetitive Peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V	
Surge Peak reverse voltage	VRSM	35	70	140	280	420	560	700		
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000		
Forward voltage @IF=1A	VF				1.1					
Max.averaged fwd.current. @ Ta =65°C	IAV				1				A	
Peak forward surge current	IFSM				25					
Maximum DC Reverse Current Ta=25°C	IR				5				μA	
Ta=125°C					100					
Typical Junction Capacitance *1	Cj				4				pF	
Thermal Resistance Junction to Ambient*2	R _{θ JA}				180				°C/W	
Junction temperature	T _j				150				°C	
Storage temperature	T _{stg}				-55 to 150					

* 1 Measured at 1 MHz and applied reverse voltage of 4 V D.C

* 2 Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P.C.B. mounted

■ Marking

NO.	1N4001FH	1N4002FH	1N4003FH	1N4004FH	1N4005FH	1N4006FH	1N4007FH
Marking	A1	A2	A3	A4	A5	A6	A7

General Purpose Silicon Rectifiers

1N4001FH ~ 1N4007FH

■ Typical Characteristics

Fig.1 Forward Current Derating Curve

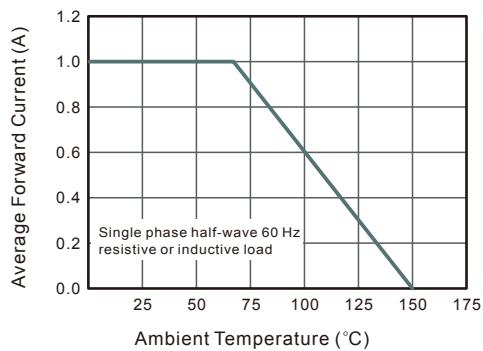


Fig.2 Typical Instantaneous Reverse Characteristics

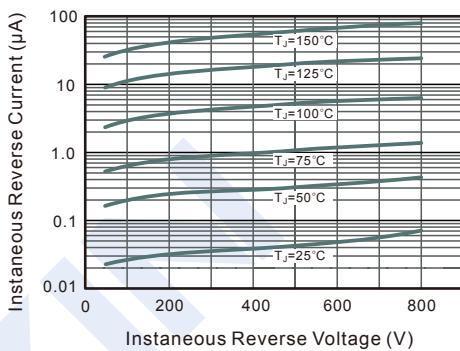


Fig.3 Typical Forward Characteristic

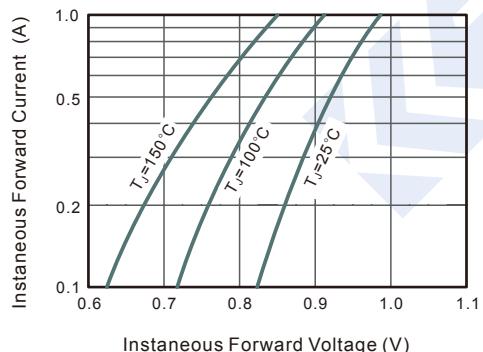
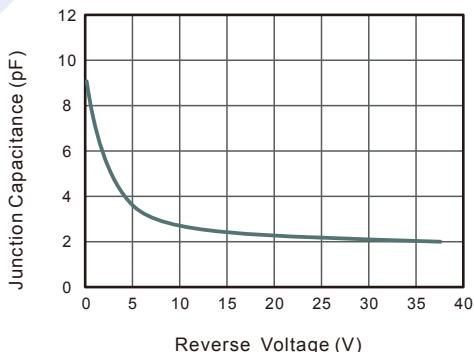


Fig.4 Typical Junction Capacitance

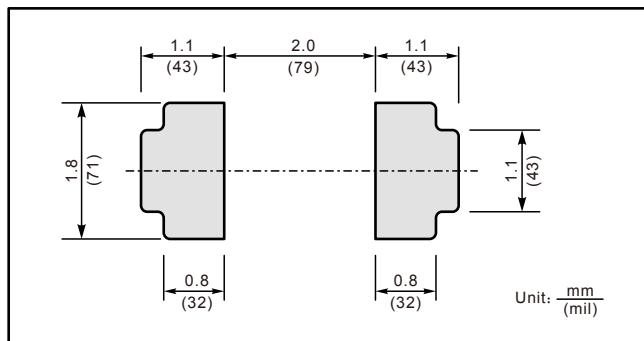
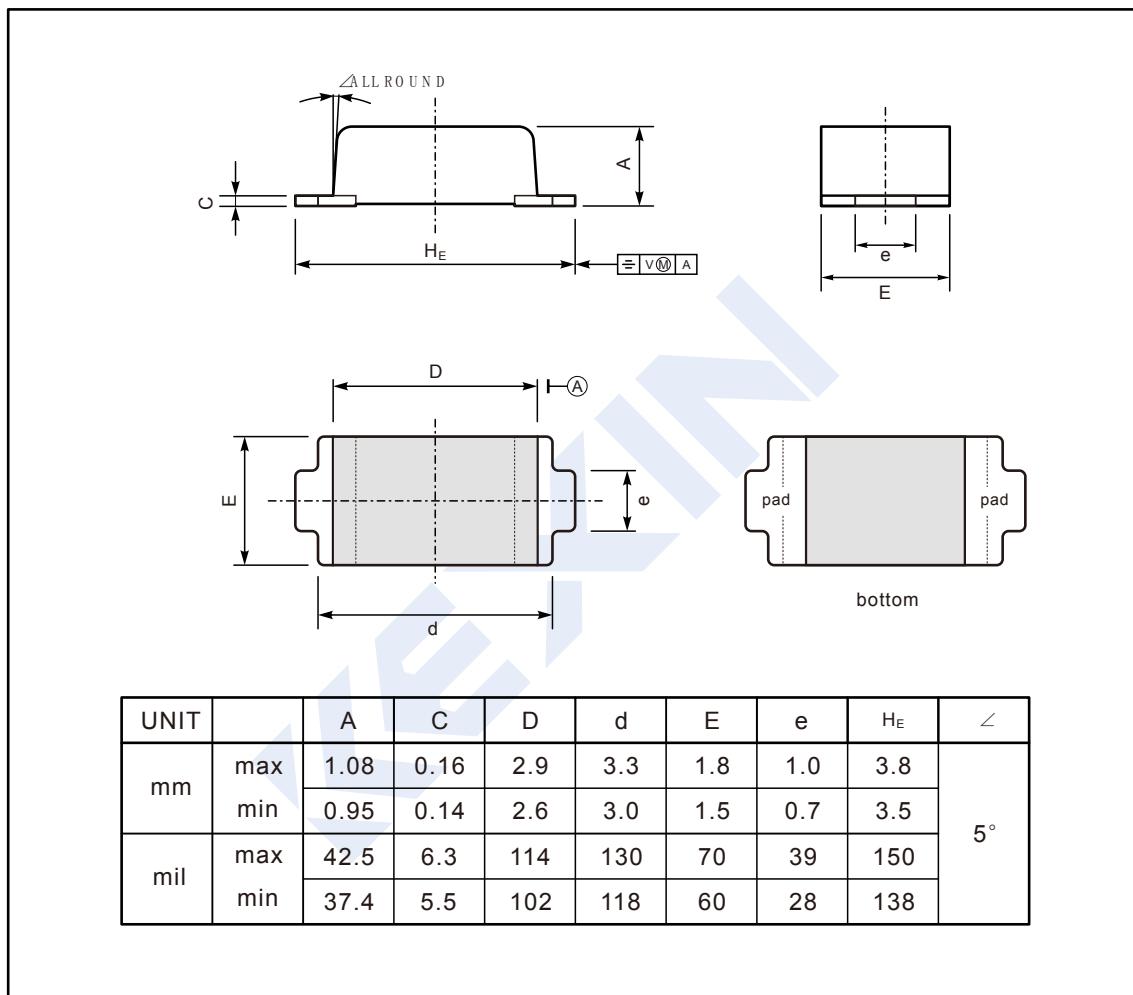


General Purpose Silicon Rectifiers

1N4001FH ~ 1N4007FH

■ Typical Application

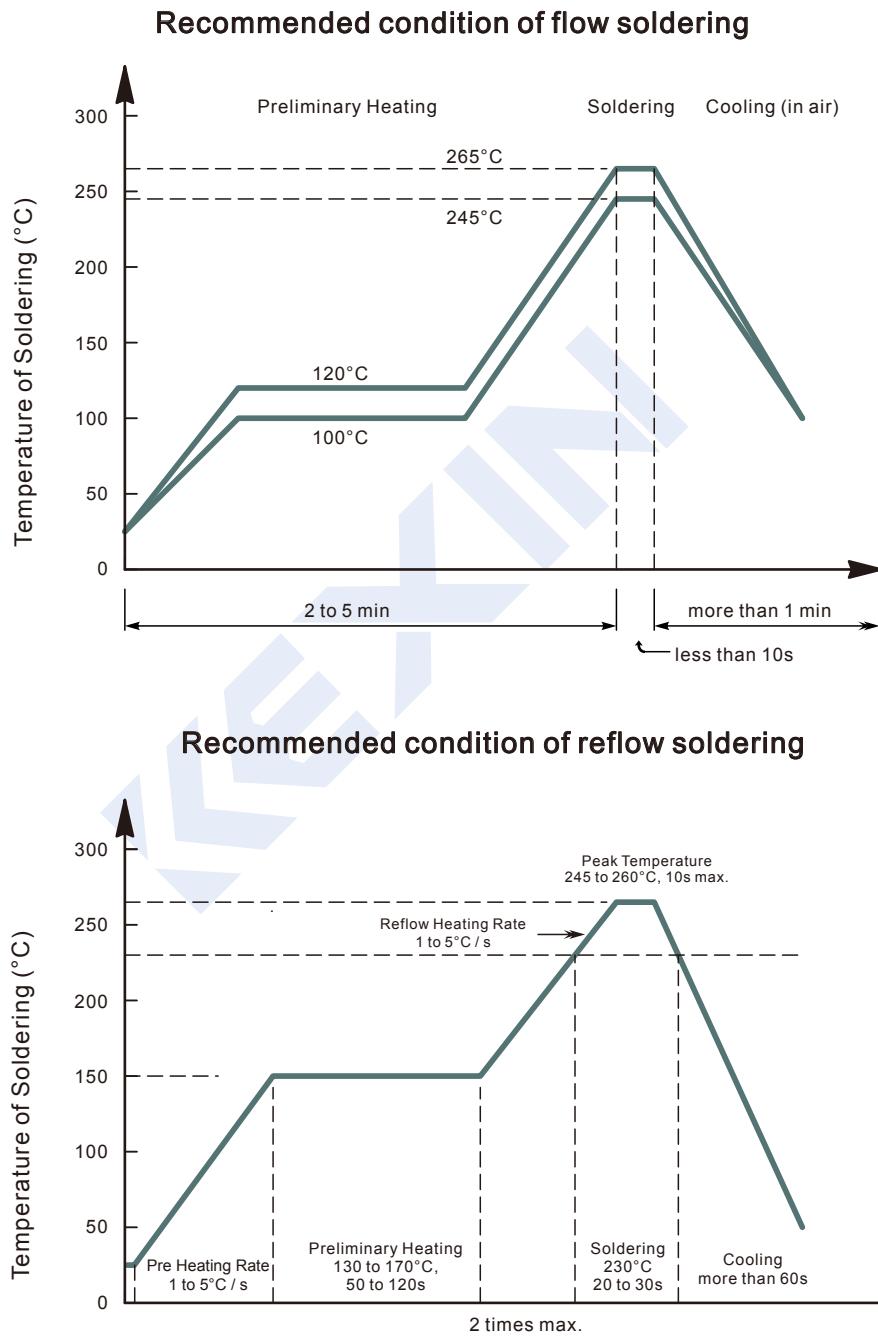
Plastic surface mounted package; 2 leads



General Purpose Silicon Rectifiers

1N4001FH ~ 1N4007FH

■ Typical Application



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters; time length of peak temperature (longer), time length of soldering (longer), thickness of solder paste (thicker)